Making Graphene Luminescent by Oxygen Plasma Treatment

T. Gokus,† R. R. Nair,‡,* A. Bonetti,§ M. Böhmler,† A. Lombardo,§ K. S. Novoselov,‡ A. K. Geim,‡ A. C. Ferrari,§,* and A. Hartschuh†,*

†Chemistry and Biochemistry Department and CeNS, Ludwig-Maximilians-University of Munich, 80539 Munich, Germany, ‡Department of Physics and Astronomy, Manchester University, Manchester M13 9PL, U.K., and §Department of Engineering, University of Cambridge, Cambridge CB3 0FA, U.K.

Graphene is at the center of a significant research effort.¹ Near-ballistic transport at room temperature and high mobility²–⁴ make it a potential material for nanoelectronics,⁵,⁶ especially for high-frequency applications.⁷ Furthermore, its optical and mechanical properties are ideal for micro- and nanomechanical systems, thin-film transistors, transparent and conductive composites and electrodes,⁸–¹⁰ and photonics.¹¹ There are two main avenues to modify the electronic structure of graphene. One is by cutting it into ribbons and quantum dots,⁵,⁶,¹²–¹⁴ and the other is by means of chemical or physical treatments with different gases to reduce the connectivity of the electron network.¹⁵,¹⁶ One of the most popular insulating chemical derivatives is graphene oxide (GO).¹⁶ Bulk GO solutions and solids do also show a broad luminescence background.¹⁷,¹⁸ Hydrogen plasma was used to controllably and reversibly modulate the electronic properties of individual graphene flakes, turning them into insulators.¹⁵ Aggressive oxygen treatment was applied to create graphene islands.¹⁹ However, thus far, no photoluminescence (PL) was seen from individual graphene layers, either cut into ribbons or dots or chemically treated, making graphene integration into optoelectronics still elusive.

Here, we show that PL can be induced in single-layer graphene using an oxygen plasma treatment. The PL is spatially uniform across the flakes and connected to elastic scattering spectra distinctly different from those of gapless pristine graphene. Oxygen plasma can be used to selectively convert the topmost layer when multilayer samples are treated.

ABSTRACT We show that strong photoluminescence (PL) can be induced in single-layer graphene using an oxygen plasma treatment. The PL is spatially uniform across the flakes and connected to elastic scattering spectra distinctly different from those of gapless pristine graphene. Oxygen plasma can be used to selectively convert the topmost layer when multilayer samples are treated.

KEYWORDS: graphene · photoluminescence · optical properties

RESULTS AND DISCUSSION

Graphene samples are produced by microcleavage of graphite on a silicon substrate covered with 100 nm SiO₂.¹ The number of layers is determined by a combination of optical microscopy and Raman spectroscopy.²⁰,²¹ Optical imaging at 473 and 514 nm is done in an inverted confocal microscope. The beam is reflected by a splitter and focused with a high numerical aperture objective (NA = 0.95). Raman spectra are measured at 514 nm with a Renishaw micro-Raman spectrometer. The samples are then exposed to oxygen/argon (1:2) RF plasma (0.04 mbar, 10 W) for increasing time (1–6 s). The structural and optical changes are monitored by Raman spectroscopy and elastic light scattering. The PL decay dynamics is recorded by time-correlated single photon counting (TCSPC) upon pulsed excitation at 530 nm (2.34 eV), with a time resolution of ±3 ps. The acquisition time per pixel is of the order of a few tens of milliseconds. The spatial resolution is ~800 nm.

Spatially resolved PL shows bright and localized emission for short treatment times (Figure 1a). For longer times, the PL is strong and spatially homogeneous (Figure 1b), with a single broad band centered at ~700 nm (1.77 eV) (Figure 1c). Intense laser excitation with power exceeding 1 mW leads to photobleaching and a PL maximum blue...
The excited state decay dynamics of this photoluminescent graphene (PLG) is complex. The PL transients of Figure 1d can be described by a three-exponential decay with lifetimes ~40, 200, and 1000 ps, much longer than those observed in semiconducting nanotubes and amorphous carbon.22,23 Remarkably, the PL transients are nearly uniform across the complete spectrum. This implies that spectral diffusion due to energy migration, typical for heterogeneously broadened systems, is absent (see Figure 6 in Methods).

A Raman investigation gives further insights into the evolution from pristine graphene to PLG. Figure 2 plots the Raman spectra and the main fitting parameters (see Methods). A broad PL background is evident in Figure 2a for treatment times above 2 s. This is different from the case of the hydrogen plasma treated samples of ref 15, where no luminescence was observed for the same excitation and detection energy range. Figure 2a also shows a significant increase of the D and D’ intensities, and the D + D’ combination mode at ~2950 cm⁻¹, which requires a defect for its activation. Note that in defected graphene the relaxation of the backscattering condition results in significant broadening of the second-order modes. Defect scattering also broadens the first-order peaks, eventually merging G and D’ in a single wide G band for treatment times above 1 s.

Figure 2b plots the evolution of the D to G peak intensity ratio, I(D)/I(G). This first raises and then decreases for increasing time. The D peak intensity is a measure of the number of defects24,25 (see Methods). Reference 25 noted that I(D)/I(G) varies inversely with the cluster size Lₐ in poly- and nanocrystalline graphites: I(D)/I(G) = C(λ)/Lₐ, where C(514.5 nm) ~ 4.4 nm.25,26 This is known as the Tuinstra and Koenig relation (TK). TK holds until a critical defect density.24 Indeed, ref. 24 noted that, since the D peak requires the presence of six-fold rings, when the network starts losing them, I(D) decreases with decreasing Lₐ.24 In this case, I(D)/I(G) = C’(λ)Lₐ², with C’(514.5 nm) ~ 0.55 nm⁻².24 Combining the latter with TK, we deduce that Figure 2b shows a con-
tinuous $L_a$ decrease down to $\sim 1$ nm and a transition to a network with fewer six-fold rings for treatment longer than 1 s. This is further validated by considering the evolution of the full width at half-maximum of the G peak, FWHM(G). In defect-free graphene, a variation of FWHM(G) is observed as a consequence of doping. However, in the case of defected samples, peak broadening is a result of the activation of $q \neq 0$ phonons. An empirical correlation between FWHM(G) and $L_a$ was reported in ref 30 considering a variety of disordered and amorphous carbons. Comparing FWHM(G) in Figure 2c with the trend in ref 30, again we get $L_a \sim 1$ nm for the longest treatment. The large FWHM(G) also implies a distribution of $L_a$ around the average value.

The ratio of the slope of the PL background ($m$) to $I(G)$ is often used in disordered carbons as a measure of the PL strength when comparing different samples. We thus plot $m/I(G)$ in Figure 2d. This reaches a maximum, then decreases for the longest treatment, consistent with the lack of PL in ref 19 after oxygen treatment targeted at layer removing.

White-light scattering spectroscopy of PLG reveals clear differences to pristine graphene. Figure 3 illustrates the scattering spectra of both materials on SiO$_2$/Si. While pristine graphene appears dark throughout the spectral range covered in the experiment, corresponding to a negative interferometric contrast, PLG shows weaker contrast with a positive sign for wavelengths smaller than 580 nm. The spectrum of PLG yields the complex refractive index $n' = A_0 + B_0/\lambda^2 + i^n(A_1 + B_1/\lambda^2)$, with Cauchy parameters $A_0 = 2.76$, $A_1 = 0.06$, $B_0 = 3000$, and $B_1 = 1500$ (assuming graphene thickness of 0.34 nm), comparable to those obtained for GO.

The data presented so far are taken for single-layer graphene (SLG). A different behavior is observed for multilayer graphene (MLG), which remains nonluminescent following treatment. Indeed, PL intensity and scattering contrast are directly correlated, as seen in Figure 4 for flakes of different thickness. The scattering contrast for treated MLG does not scale linearly with the number of layers, as in the case of pristine SLG. The MLG spectrum only features negative contrast, while the positive contribution below 580 nm observed for PLG is absent. Scattering spectra from treated MLG can be represented by a superposition of treated and pristine SLG.

Oxygen plasma etching of graphite proceeds layer-by-layer. Thus, in our case, only the topmost layer is affected. The absence of PL in MLG means that emission from the topmost layer is quenched by subjacent untreated layers. This opens the possibility of engineering sandwiched hybrid structures consisting of PLG and a variable number of pristine graphene layers.

Oxygen plasma etching is expected to yield CO and CO$_2$ by successively removing carbon atoms. Etching of graphite occurs both in the basal plane and at defects. The latter is consistent with our observation of point-like PL features for short treatment times (Figure 1a).

It would be tempting to interpret the PL emission as coming from electron confinement in $sp^2$ islands.
with an average size of \( \sim 1 \) nm, as indicated by Raman spectroscopy. Indeed, since electrons in graphene behave as massless particles, energy quantization due to confinement is expected to open a gap \( \delta E \approx \frac{\hbar v_F}{2d} \approx 2eVnm/d \). The resulting quantum confined energy for a quantum disk of diameter \( d = 2 \) nm is 1 eV. The observed emission energy distribution translates into a diameter distribution ranging from 0.94 to 1.29 nm, in agreement with the Raman estimation. In this case, the large spectral width of the PL signal, \( \sim 0.5 \) eV, could result from a superposition of overlapping bands with narrow linewidth centered at different size-controlled (or quantum confined) energies, corresponding to heterogeneous broadening. Then, the optical properties of the PLG would resemble those of \( \pi \)-conjugated polymer films, where a distribution of conjugation lengths translates into a strong inhomogeneously broadened density of states. At room temperature, laser irradiation in the red would lead to selective excitation of a subset of quantum confined states. Then, spectral hole burning (i.e., the selective photobleaching of this subset of homogeneously broadened lines) should be possible. This bleaching could be a photochemical modification or even a complete removal of the absorbing subset. As a result, we would observe a spectral hole, i.e., the subset absorbing a certain color would not contribute to PL. Figure 5 plots the ratio of PL measured before \( (I_{PL}) \) and after \( (I_{PL,bleached}) \) exposure to high power (\( \geq 600 \) \( \mu \)W) pulsed laser light at 647 nm. The PL is measured at 530 nm for low excitation power (\( \sim 10 \) \( \mu \)W). No spectral hole is observed in the detected spectral range (760, 800 nm), the same uniform decrease is observed, while in the blue (473, 514 nm), the PL slightly shifts to shorter wavelength (see Figure 1c).

Thus, we find that the observed large spectral width of 0.5 eV reflects mainly homogeneous broadening of a single emissive species, uniform across the PLG sheet. This is supported by the absence of spectral diffusion in the time-resolved data, expected for heterogeneous films (see Methods). If PL would indeed result from quantum confined states, size-related heterogeneous broadening would need to be far smaller, probably below 0.1 eV, requiring a very narrow size distribution of \( \sim \pm 0.04 \) nm, instead of the \( \sim \pm 0.18 \) nm needed for the 0.5 eV broadening. Since oxidation is expected to occur at different lattice sites and configurations, such high degree of ordering would seem unreasonable. Moreover, while for increasing oxidation times a successive decrease of size distribution would be expected, the spectral characteristics of the PL emission remain nearly constant. Thus, although the identification of \( L_2 \) as the quantum confinement length of massless electrons would be tempting, we rather assign the observed PL to CO-related localized electronic states at the oxidation sites.

CONCLUSIONS

We have shown that spatially uniform PL can be induced in single-layer graphene on substrates by selective plasma oxidation. Remarkably, bi- and multilayer flakes remain nonluminescent, while their elastic scattering spectra indicate the formation of sandwich-like structures containing unetched layers. The resulting photoluminescent material could pave the way toward graphene-based optoelectronics.

METHODS

Raman Background. Raman spectroscopy is a fast and nondestructive method for the characterization of carbons. These show common features in the 800–2000 cm\(^{-1}\) region: the G and D peaks. The G peak corresponds to the \( E_{2g} \) phonon at the Brillouin zone center. The D peak is due to the breathing modes of \( sp^2 \) rings and requires a defect for its activation.\(^{24,25,36}\) It comes from TO phonons around \( K \),\(^{24,25}\) is active by double resonance (DR), and is strongly dispersive with excitation energy due to a Kohn Anomaly at \( K \).\(^{25}\) The 2D peak is the second order of the
D peak. This is a single band in monolayer graphene, whereas it splits in four in bilayer graphene, reflecting the evolution of the band structure.\textsuperscript{11} The 2D peak is always seen, even when no D peak is present; since no defects are required for the activation of two phonons with the same momentum, one backscattering from the other. DR can also happen as intravalley process, i.e., connecting two points belonging to the same cone around \( K \) or \( K' \). This gives rise to the D’ peak, \( \sim 1620 \text{ cm}^{-1} \) in defected graphite. The 2D’ is the second order of the D’ peak.

Reference 25 noted that \((\text{ID})/(\text{IG})\) varies inversely with the cluster size, \( L_{\text{c}} \), in poly- and nanocrystalline graphite: \((\text{ID})/(\text{IG}) = C/(\lambda L_{\text{c}}) \), where \( C(514.5 \text{ nm}) \sim 4.4 \text{ nm}^{24,25}\). The original idea was to link ID to phonon confinement. The intensity of the nonallowed D peak would be ruled by the defect-induced lifting of the Raman fundamental selection rule. Assuming that graphite below allowed D peak would be ruled by the defect-induced lifting of the vibration is due to DR and not to phonon confinement. However, we note that a complete theory for the effective to compare graphitic samples for increasing disorder.\textsuperscript{24,30,31} However, we note that a complete theory for the effective to compare graphitic samples for increasing disorder.

Figure 6 plots the PL transients measured at four detection energies after excitation at 530 nm. These are nearly uniform across the complete spectrum, indicating that spectral diffusion due to energy migration, typical for heterogeneously broadened systems, is absent.

PL Transients. Figure 6 plots the PL transients measured at four different detection energies after excitation at 530 nm. All can be modeled by a triexponential decay with decay constants of 40, 250, and \( 1000 \text{ ps} \), with different relative contributions. Remarkably, there is no direct correlation between emission energy and decay dynamics, as could be expected for heterogeneously broadened systems. In this case, spectral diffusion due to energy migration would lead to faster decay in the blue spectral range and a delayed signal rise on the same time scale in the red.\textsuperscript{24} The decay traces can also be modeled using a stretched-exponential function.

Acknowledgment. A.C.F., K.S.N., and A.K.G. thank the Royal Society and the European Research Council (Grants NANOPOTS and GRAPHENE), A.H. the Deutsche Forschungsgemeinschaft (DFG-grant HU4405/4-1) and Nanosystems Initiative Munich (NIM), A. L. from the University of Palermo, Italy.

REFERENCES AND NOTES


